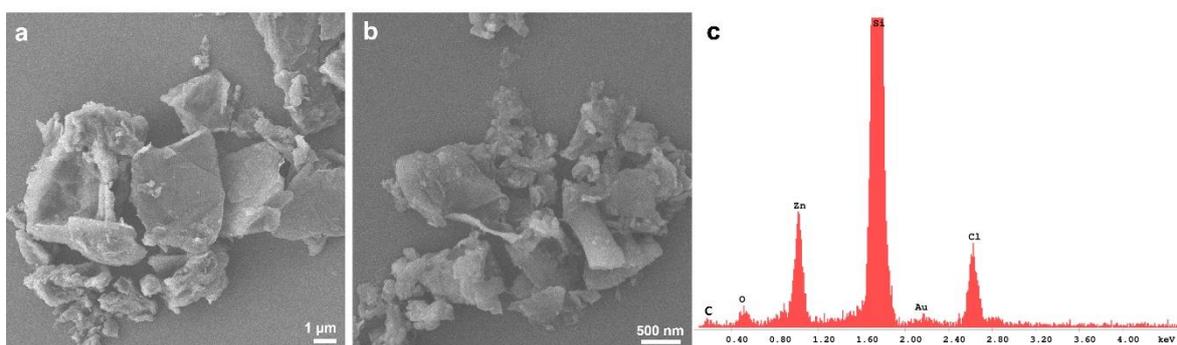


*Supplementary Information for*

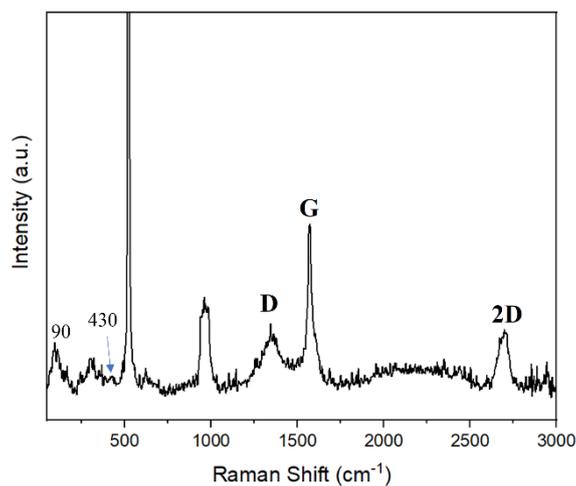
**Scalable Solid-State Synthesis of 2D Transition Metal Oxide/Graphene Hybrid Materials and their Utilization for Microsupercapacitors**

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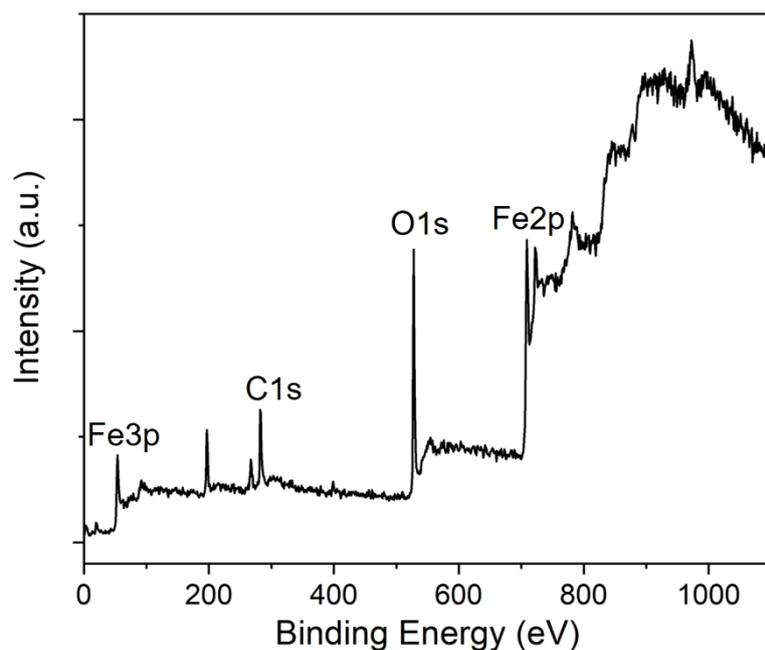


**Fig. S1** SEM images (a-b) and EDX spectrum of 2D ZnO/rGO (10/1) nanocomposite.

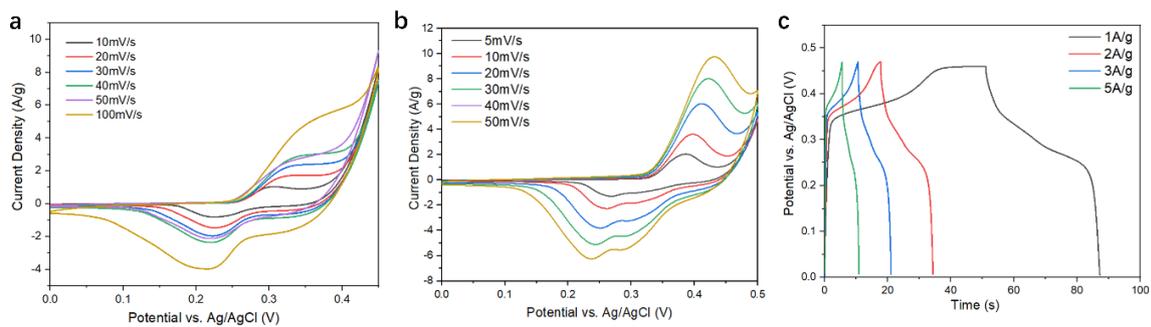


**Fig. S2** Raman spectrum of 2D ZnO/rGO (10/1) nanocomposite.

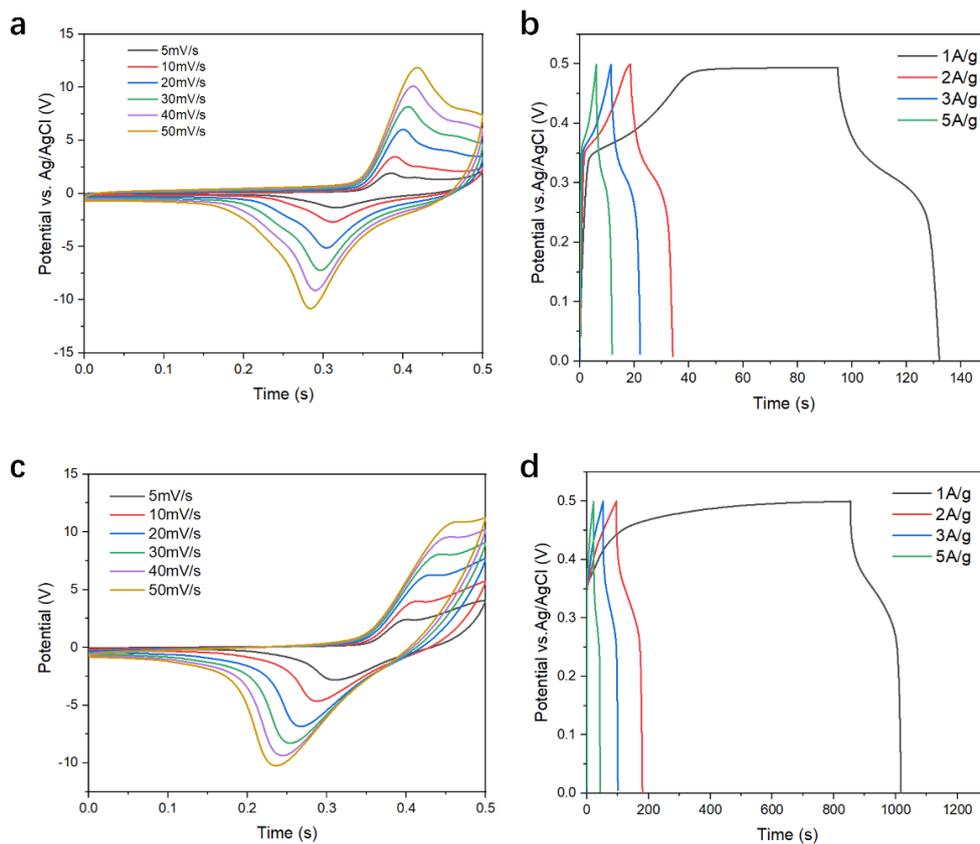
\* Corresponding author email: weinanxu@uakron.edu



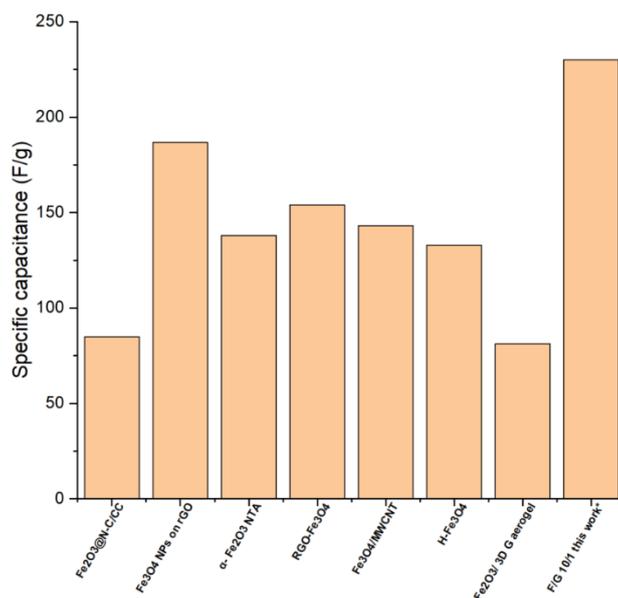
**Fig. S3** XPS survey scan of the 2D  $\text{Fe}_2\text{O}_3/\text{rGO}$  (10/1) nanocomposite.



**Fig. S4** (a) CV scans of 2D  $\text{Fe}_2\text{O}_3$  at scan rates from 10mV/s to 100mV/s. (b) CV scans of 2D  $\text{Fe}_2\text{O}_3/\text{rGO}$  (20/1) with scan rates from 5mV/s to 50mV/s. (c) GCD curves of 2D  $\text{Fe}_2\text{O}_3/\text{rGO}$  (20/1) with rates from 1A/g to 5A/g.



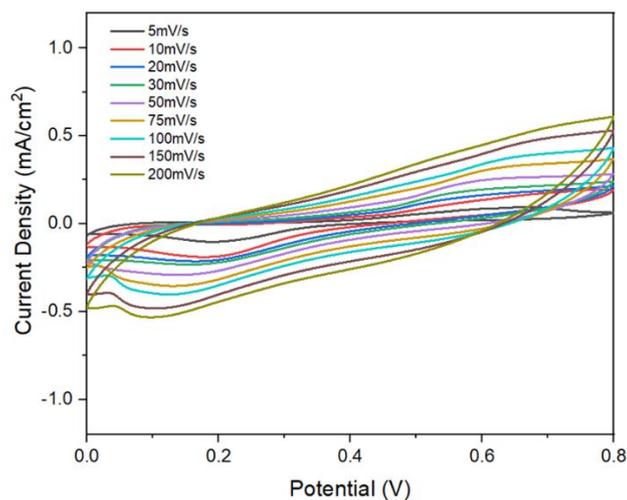
**Fig. S5** Electrochemical behavior of 2D ZnO/rGO nanocomposites in 3 electrode test. (a) CV scans of 2D ZnO/rGO (100/1) from 5mV/s to 50mV/s. (b) GCD curves of 2D ZnO/rGO (100/1) from 1A/g to 5A/g, (c) CV curves of ZnO/rGO (10/1) from 5mV/s to 50mV/s. (d) GCD curves of 2D ZnO/rGO (10/1) from 1A/g to 5A/g.



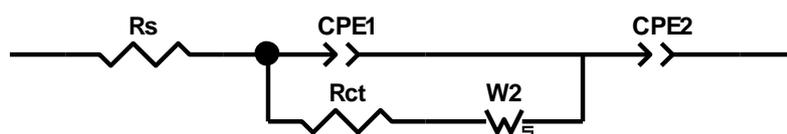
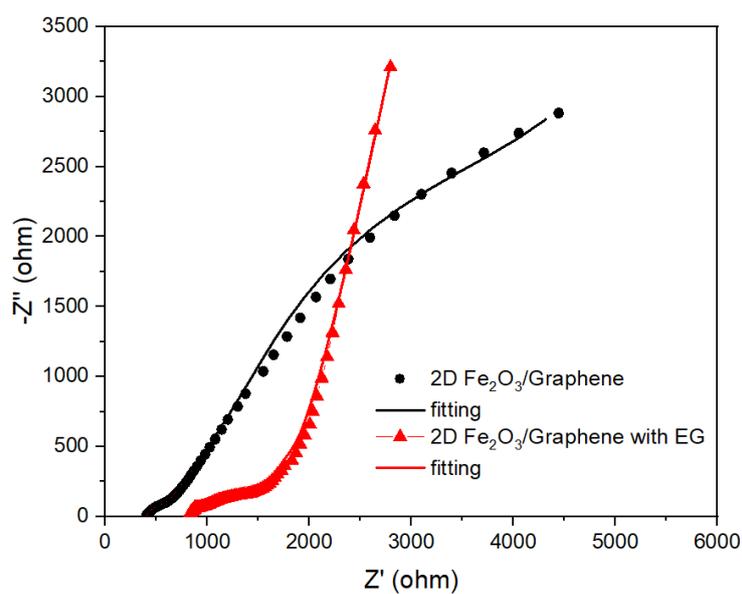
**Fig. S6** Specific capacitance of the 2D Fe<sub>2</sub>O<sub>3</sub>/rGO (10/1) nanocomposite in this study compared with relevant literature results.

**Table S1 Comparison of the specific capacitance of 2D Fe<sub>2</sub>O<sub>3</sub>/G with other literatures**

<b>Materials and structure</b>	<b>Synthetic Method</b>	<b>Specific capacitance</b>	<b>Electrolyte</b>	<b>Reference number</b>
Fe <sub>3</sub> O <sub>4</sub> nanoparticle on rGO sheet	Electrophoretic deposition and electrochemical reduction	154 F/g at 1A/g	0.5M Na <sub>2</sub> SO <sub>4</sub>	70
Iron oxide nanoneedles on N-doped carbon nanoarray	Hydrothermal synthesis	85 F/g at 1A/g 183.8 mF/cm <sup>2</sup> at 3mA/cm <sup>2</sup>	1M KOH	72
Fe <sub>3</sub> O <sub>4</sub> nanoparticles on rGO	Hydrothermal synthesis	220.1 F/g at 0.5A/g	1M KOH	73
Iron oxide nanotube array	Anodization and annealing	138 F/g at 1.3A/g	1M Li <sub>2</sub> SO <sub>4</sub>	74
Fe <sub>3</sub> O <sub>4</sub> nanoparticles covered MWCNTs	Multi-step chemical synthesis	143 F/g at 1A/g	1M KCl	75
H-Fe <sub>3</sub> O <sub>4</sub> nanoparticles	Hydrothermal synthesis and ultrasonication	207.7 F/g at 0.4A/g	1M Na <sub>2</sub> SO <sub>3</sub>	76
Nano-iron oxide/3D graphene aerogel	Hydrothermal synthesis	81.3 F/g at 1A/g	0.5M Na <sub>2</sub> SO <sub>4</sub>	77
2D Fe <sub>2</sub> O <sub>3</sub> /rGO	Solid state microwave synthesis	331.4 F/g at 1mV/s 230.1F/g at 1A/g	1M KOH	This work



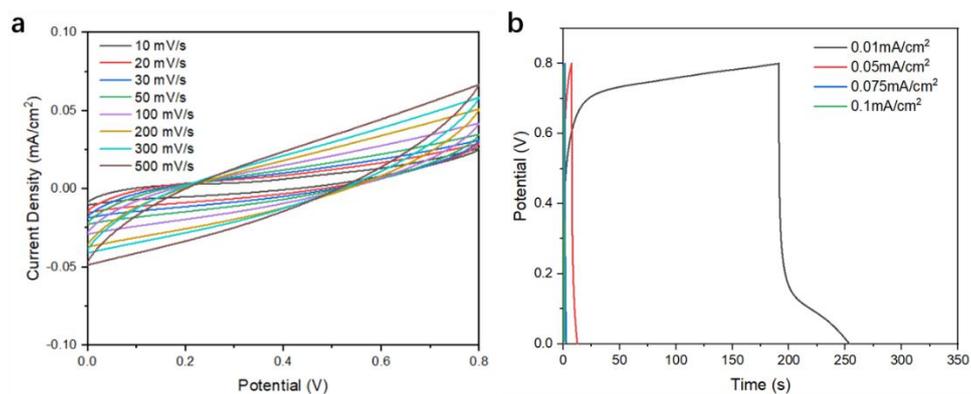
**Fig. S7** Cyclic Voltammetry scans of symmetric device fabricated with only 2D Fe<sub>2</sub>O<sub>3</sub>/G at different scan rate from 5mV/s to 200mV/s.



**Fig. S8** Nyquist plots and fitting from EIS measurements (top), as well as the equivalent circuit diagram used for data fitting (bottom).

**Table S2** EIS data fitting results

	<b>Rs</b>	<b>Rct</b>	<b>W-R</b>	<b><math>\chi</math> square</b>
<b>2D Fe<sub>2</sub>O<sub>3</sub>/rGO</b>	384.1	817.5	28017	0.00299
<b>2D Fe<sub>2</sub>O<sub>3</sub>/rGO with EG</b>	750.9	1506	428	0.00134



**Fig. S9** Electrochemical behavior of symmetric device fabricated by spray coating. (a) CV scans from 10mV/s to 500mV/s. (b) GCD curves from 0.01A/g to 0.1A/g,

## Capacitance Calculation

Specific capacitance was calculated from both CV curves and discharge curves in 3 electrode test, using the following equation:

$$C_S = \frac{\int_{V_1}^{V_2} IdV}{mv(V_2-V_1)} \quad (1)$$

Where  $C_S$  is the gravimetric capacitance,  $V_1$  and  $V_2$  is the lowest limit and highest limit of the potential window,  $m$  is the total weight of active materials and  $v$  is the scan rate in CV test.

For GCD result, specific capacitance was calculated following:

$$C_S = \frac{I \int V dt}{m(\Delta V)^2} \quad (2)$$

Where  $I$  is the constant current during the test,  $\int V dt$  is the integrated area of the discharge curve,  $m$  is the total weight, and  $\Delta V$  is the potential drop over discharging process.

In two electrode test, the specific capacitance of the planar devices were calculated via

$$C_A = \frac{2 \int_{V_1}^{V_2} IdV}{Av(V_2-V_1)} \quad (3)$$

Where  $A$  is the active area of the electrode, the factor two is because the series capacitance formation in 2-electrode system.